

CMOS Digital Integrated Circuits Silicon Monolithic

## 74VHC4051AFT,74VHC4052AFT,74VHC4053AFT

#### 1. Functional Description

74VHC4051AFT:8-Channel Analog Multiplexer/Demultiplexer 74VHC4052AFT:Dual 4-Channel Analog Multiplexer/Demultiplexer 74VHC4053AFT:Triple 2-Channel Analog Multiplexer/Demultiplexer

#### General

The 74VHC4051AFT, 74VHC4052AFT and 74VHC4053AFT are high-speed, low-voltage drive analog multiplexer/demultiplexers using silicon gate CMOS technology. In 3 V and 5 V systems these can achieve highspeed operation with the low power dissipation that is a feature of CMOS.

The~74VHC4051AFT, 74VHC4052AFT~and~74VHC4053AFT~offer~analog/digital~signal~selection~as~well~as~mixed~algorithm and the standard contraction of the standard contractinsignals. The 74VHC4051AFT has an 8-channel configuration, the 74VHC4052AFT has an 4-channel ×2 configuration, and the 74VHC4053AFT has a 2-channel ×3 configuration.

The switches for each channel are turned ON by the control pin digital signals.

All control inputs are equipped with a newly developed input protection circuit that avoids the need for a diode on the plus side (forward side from the input to the  $V_{\rm CC}$ ). As a result, for example, 5.5 V signals can be permitted on the inputs even when the power supply voltage to the circuits is off. As a result of this input power protection, the 74VHC4051AFT, 74VHC4052AFT and 74VHC4053AFT can be used in a variety of applications, including in the system which has two power supplies, and in battery backup circuits.

#### 3. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- Wide operating temperature range:  $T_{opr} = -40$  to 125 °C
- Low ON-resistance:  $R_{\rm ON}$  = 45  $\Omega$  (typ.) (V\_{\rm CC} = 3.0 V)

$$R_{ON} = 24 \Omega \text{ (typ.) } (V_{CC} = 4.5 \text{ V})$$

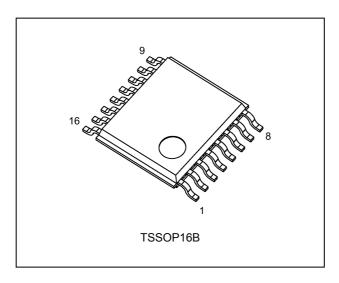
- Low power dissipation:  $I_{CC} = 2.0 \mu A \text{ (max)} \text{ (}T_a = 25^{\circ}\text{C)}$ (4)
- High noise immunity:  $V_{IL} = 0.8 \text{ V (max)} V_{CC} = 3.0 \text{ V}$

$$V_{IH} = 2.0 \text{ V (min) } V_{CC} = 3.0 \text{ V}$$

Power down protection is provided on all control inputs.

Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales

#### 4. Packaging



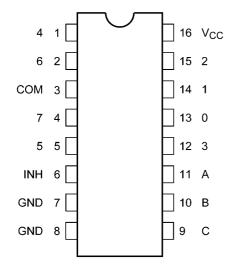
Start of commercial production

2013-06

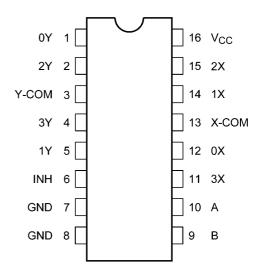


## 5. Pin Assignment

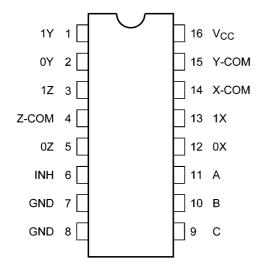
#### 74VHC4051AFT



#### 74VHC4052AFT

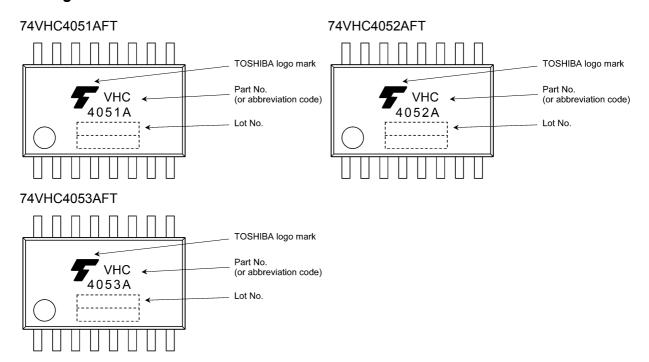


74VHC4053AFT





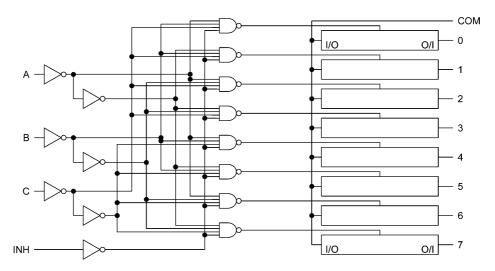
## 6. Marking



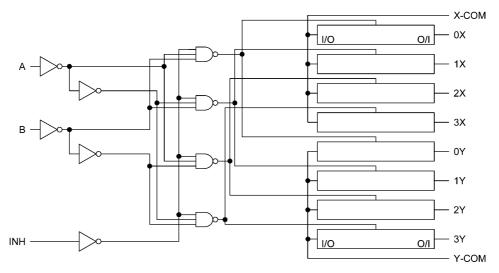


## 7. System Diagram

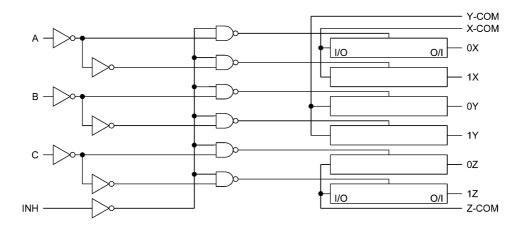
74VHC4051AFT



74VHC4052AFT



#### 74VHC4053AFT





#### 8. Truth Table

Input Inhibit	Input C*	Input B	Input A	ON Channel 74VHC4051AFT	ON Channel 74VHC4052AFT	ON Channel 74VHC4053AFT
L	L	L	L	0	0X, 0Y	0X, 0Y, 0Z
L	L	L	Н	1	1X, 1Y	1X, 0Y, 0Z
L	L	Н	L	2	2X, 2Y	0X, 1Y, 0Z
L	L	Н	Н	3	3X, 3Y	1X, 1Y, 0Z
L	Н	L	L	4	_	0X, 0Y, 1Z
L	Н	L	Н	5	_	1X, 0Y, 1Z
L	Н	Н	L	6	_	0X, 1Y, 1Z
L	Н	Н	Н	7	_	1X, 1Y, 1Z
Н	Х	Х	Х	None	None	None

X: Don't care

Except 74VHC4052AFT

### 9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		-0.5 to 7.0	V
Input voltage	V <sub>IN</sub>		-0.5 to 7.0	V
Switch I/O voltage	V <sub>I/O</sub>		-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>		-20	mA
I/O diode current	I <sub>I/OK</sub>		±25	mA
Switch through current	I <sub>T</sub>		±25	mA
V <sub>CC</sub> /ground current	I <sub>CC</sub>		±50	mA
Power dissipation	P <sub>D</sub>	(Note 1)	180	mW
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: 180 mW in the range of  $T_a$  = -40 to 85 °C. From  $T_a$  = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

#### 10. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	V <sub>CC</sub>		2.0 to 5.5	V
Input voltage	V <sub>IN</sub>		0 to 5.5	V
Switch I/O voltage	Vs		0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>		-40 to 125	°C
Input rise and fall times	dt/dv	$V_{CC} = 2.5 \pm 0.2 \text{ V}$	0 to 200	ns/V
		$V_{CC}$ = 3.3 ± 0.3 V	0 to 100	
		V <sub>CC</sub> = 5 ± 0.5 V	0 to 20	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V<sub>CC</sub> or GND.

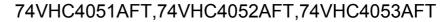
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### 11. Electrical Characteristics

## 11.1. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

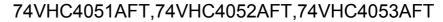
Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
High-level input voltage	V <sub>IH</sub>	_	2.0	1.5	_	_	V
			3.0	2.0	_	_	
			4.5	3.15	_	_	
			5.5	3.85	_	_	
Low-level input voltage	V <sub>IL</sub>	_	2.0	_	_	0.5	V
			3.0	_	_	0.8	
			4.5	_	_	1.35	
			5.5	_	_	1.65	
ON-resistance	R <sub>ON</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	2.3	_	200	_	Ω
		$V_{I/O} = V_{CC}$ to GND $I_{I/O} = 2 \text{ mA}$	3.0	_	45	86	
			4.5	_	24	37	
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	2.3	_	28	73	
		$V_{I/O} = V_{CC}$ or GND $I_{I/O} = 2 \text{ mA}$	3.0	_	22	38	
		11/0 - 2111A	4.5	_	17	27	
Difference of ON-resistance	$\Delta R_{ON}$		2.3	_	10	25	Ω
between switches		$V_{I/O} = V_{CC}$ to GND $I_{I/O} = 2 \text{ mA}$	3.0	_	5	15	
		11/0 - 2 111A	4.5	_	5	13	
Input/Output leakage current (Switch OFF)	I <sub>OFF</sub>	$V_{OS} = V_{CC}$ or GND $V_{IS} = GND$ to $V_{CC}$ $V_{IN} = V_{IH}$ or $V_{IL}$	5.5	_	_	±0.1	μА
Input/Output leakage current (Switch ON, Output OPEN)	I <sub>I/O</sub>	V <sub>OS</sub> = V <sub>CC</sub> or GND V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	5.5	_	_	±0.1	μА
Control input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	_	_	±0.1	μА
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	_	_	2.0	μА





## 11.2. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = -40 to 85 °C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_	2.0	1.5	_	V
			3.0	2.0	_	
			4.5	3.15	_	
			5.5	3.85	_	
Low-level input voltage	V <sub>IL</sub>	_	2.0	_	0.50	V
			3.0	_	0.8	
			4.5	_	1.35	
			5.5	_	1.65	
ON-resistance	R <sub>ON</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	2.3	_	_	Ω
		$V_{I/O} = V_{CC}$ to GND $I_{I/O} = 2 \text{ mA}$	3.0	_	108	
			4.5	_	46	
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	2.3	_	84	
		$V_{I/O} = V_{CC}$ or GND	3.0	_	44	
		$I_{I/O} = 2 \text{ mA}$	4.5	_	31	
Difference of ON-resistance	$\Delta R_{ON}$		2.3	_	35	Ω
between switches		$V_{I/O} = V_{CC}$ to GND	3.0	_	20	
		$I_{I/O} = 2 \text{ mA}$	4.5	_	18	
Input/Output leakage current (Switch OFF)	I <sub>OFF</sub>	$V_{OS} = V_{CC}$ or GND $V_{IS} = GND$ to $V_{CC}$ $V_{IN} = V_{IH}$ or $V_{IL}$	5.5	_	±1.0	μА
Input/Output leakage current (Switch ON, Output OPEN)	I <sub>I/O</sub>	$V_{OS} = V_{CC}$ or GND $V_{IN} = V_{IH}$ or $V_{IL}$	5.5	_	±1.0	μА
Control input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5		±1.0	μА
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	_	20.0	μА





## 11.3. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = -40 to 125 °C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_	2.0	1.5	_	V
			3.0	2.0	_	
			4.5	3.15	_	
			5.5	3.85	_	
Low-level input voltage	V <sub>IL</sub>	_	2.0	_	0.5	V
			3.0	_	0.8	]
			4.5	_	1.35	
			5.5	_	1.65	
ON-resistance	R <sub>ON</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	2.3	_	_	Ω
		$V_{I/O} = V_{CC}$ to GND $I_{I/O} = 2 \text{ mA}$	3.0	_	125	
		11/0 - 2 IIIA	4.5	_	54	
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	2.3	_	105	]
		$V_{I/O} = V_{CC}$ or GND	3.0	_	55	
		$I_{I/O} = 2 \text{ mA}$	4.5	_	39	
Difference of ON-resistance	$\Delta R_{ON}$		2.3	_	45	Ω
between switches		V <sub>I/O</sub> = V <sub>CC</sub> to GND	3.0	_	25	
		$I_{I/O} = 2 \text{ mA}$	4.5	_	23	
Input/Output leakage current (Switch OFF)	I <sub>OFF</sub>	$V_{OS} = V_{CC}$ or GND $V_{IS} = GND$ to $V_{CC}$ $V_{IN} = V_{IH}$ or $V_{IL}$	5.5	_	±4.0	μА
Input/Output leakage current (Switch ON, Output OPEN)	I <sub>I/O</sub>	V <sub>OS</sub> = V <sub>CC</sub> or GND V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	5.5	_	±4.0	μА
Control input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	_	±2.0	μА
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	_	40.0	μА



## 74VHC4051AFT,74VHC4052AFT,74VHC4053AFT

## 11.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Unit
Phase difference between		Ψι/Ο		$2.5 \pm 0.2$	15	_	1.2	10	ns
input to output					50		2.6	12	
				$3.3 \pm 0.3$	15	_	0.8	6	
					50	_	1.5	9	
				$5.0 \pm 0.5$	15	-	0.3	4	
					50	_	0.6	6	
Output enable time		$t_{PZL}, t_{PZH}$	$R_L = 1 k\Omega$	$2.5 \pm 0.2$	15	_	3.3	15	ns
			Figure 1		50		4.2	25	
				$3.3 \pm 0.3$	15		2.3	11	
					50	1	3.0	18	
				$5.0 \pm 0.5$	15	-	1.6	7	
					50		2.1	12	
Output disable time		$t_{PLZ}, t_{PHZ}$	$R_L = 1 k\Omega$	$2.5 \pm 0.2$	15	_	6	15	ns
	Figure 1		50	_	9.6	25			
				$3.3 \pm 0.3$	15	_	4.5	11	
					50	_	7.2	18	
				5.0 ± 0.5	15	_	3.2	7	
					50	_	5.1	12	
Control input capacitance		C <sub>IN</sub>	All types	_	_	_	2	_	pF
Common terminal capacitance	74VHC4051AFT	C <sub>IS</sub>	Figure 2	_	_	_	23.4	_	pF
	74VHC4052AFT					_	13.1	_	
	74VHC4053AFT					_	8.2	_	
Switch terminal capacitance	74VHC4051AFT	Cos	Figure 2	_	_	_	5.7	_	pF
	74VHC4052AFT					_	5.6	_	
	74VHC4053AFT					_	5.6	_	
Feedthrough capacitance	74VHC4051AFT	C <sub>IOS</sub>	Figure 2	_	_	_	0.5	_	pF
	74VHC4052AFT						0.5	_	
	74VHC4053AFT					_	0.5	_	
Power dissipation capacitance	74VHC4051AFT	C <sub>PD</sub>	Figure 2	_	_	_	15	_	pF
	74VHC4052AFT		(Note 1)			_	24	_	
	74VHC4053AFT						12		

Note 1: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$ 



# 11.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Phase difference between input to output	Φι/Ο		$2.5 \pm 0.2$	15	_	16	ns
				50	_	18	
			$3.3 \pm 0.3$	15	_	10	
				50	_	12	
			$5.0 \pm 0.5$	15	_	7	
				50	_	8	
Output enable time	$t_{PZL}, t_{PZH}$	$R_L = 1 k\Omega$	$2.5 \pm 0.2$	15	_	20	ns
		Figure 1		50	_	32	
			$3.3 \pm 0.3$	15	_	15	
				50	-	22	
			5.0 ± 0.5	15	_	10	
				50	_	16	
Output disable time	$t_{PLZ}, t_{PHZ}$	$R_L = 1 k\Omega$	$2.5 \pm 0.2$	15	_	23	ns
		Figure 1		50	_	32	
			$3.3 \pm 0.3$	15	-	15	
				50	_	22	
			5.0 ± 0.5	15		10	
				50	1	16	
Control input capacitance	C <sub>IN</sub>	_		_	_	10	pF

# 11.6. AC Characteristics (Unless otherwise specified, $T_a$ = -40 to 125 °C, Input: $t_r$ = $t_f$ = 3 ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Phase difference between input to output	ΦΙ/Ο		2.5 ± 0.2	15	_	20	ns
				50	_	22	
			$3.3 \pm 0.3$	15	_	13	
				50	_	14	
			$5.0 \pm 0.5$	15	_	9	
				50	-	9.5	
Output enable time	t <sub>PZL</sub> ,t <sub>PZH</sub>	$R_L = 1 k\Omega$	2.5 ± 0.2	15	-	23.5	ns
		Figure 1		50	_	37	
			$3.3 \pm 0.3$	15	_	18	
				50	_	25	
			$5.0 \pm 0.5$	15	_	12	
				50	_	19	
Output disable time	t <sub>PLZ</sub> ,t <sub>PHZ</sub>	$R_L = 1 k\Omega$	2.5 ± 0.2	15	-	28.5	ns
		Figure 1		50	_	37	
			$3.3 \pm 0.3$	15	_	18	
				50	_	25	
			5.0 ± 0.5	15	_	12	
				50	1	19	
Control input capacitance	C <sub>IN</sub>		_	_	-	10	pF



## 74VHC4051AFT,74VHC4052AFT,74VHC4053AFT

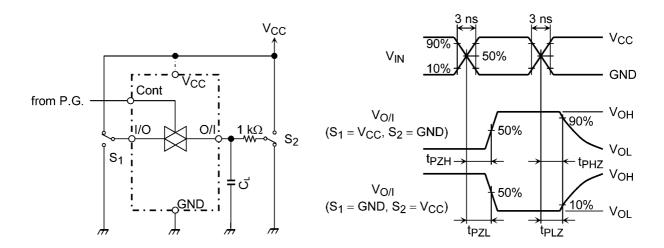
## 11.7. Analog Switch Characteristics (T<sub>a</sub> = 25 °C) (Note)

Characteristics	Part Number	Symbol	Test Condition		V <sub>CC</sub> (V)	Тур.	Unit
Sine Wave Distortion		THD	$R_L = 10 \text{ k}\Omega, C_L = 50 \text{ pF}$	$V_{IN} = 2.0 V_{p-p}$	3.0	0.1	%
			f <sub>IN</sub> = 1 kHz	$V_{IN} = 4.0 V_{p-p}$	4.5	0.03	
Maximum frequency	74VHC4051AFT	f <sub>MAX(I/O)</sub>	V <sub>IN</sub> is centered at (V <sub>CC</sub> /2).	•	3.0	150	MHz
response	74VHC4052AFT	]	Adjust input for 0 dBm. Increase f <sub>IN</sub> frequency until dB			200	
	74VHC4053AFT		meter reads -3 dB.			240	
	74VHC4051AFT	]	$R_L = 50 \Omega$ , $C_L = 10 pF$ , sine		4.5	180	
	74VHC4052AFT	]	wave Figure 3			230	
	74VHC4053AFT		i igaio o			280	
Feed through attenuation (switch OFF)		FTH	V <sub>IN</sub> is centered at (V <sub>CC</sub> /2). Adjust input for 0 dBm.		3.0	-45	dB
			$R_L = 600 \Omega$ , $C_L = 50 pF$ , $f_{IN} = 1 MHz$ , sine wave Figure 4		4.5	-45	
			$V_{IN}$ is centered at $(V_{CC}/2)$ . Adjust input for 0 dBm. $R_1 = 50 \Omega$ , $C_1 = 10 pF$ ,		3.0	-65	
			f <sub>IN</sub> = 1 MHz, sine wave Figure 4		4.5	-65	
Crosstalk (control input to signal output)		X <sub>talk</sub>	$R_L = 600 \Omega, C_L = 50 pF,$ $f_{IN} = 1 MHz,$		3.0	60	mV
			square wave (t <sub>r</sub> = t <sub>f</sub> = 6 ns) Figure 5		4.5	100	
Crosstalk (between any switches)		X <sub>talk</sub>	V <sub>IN</sub> is centered at (V <sub>CC</sub> /2). Adjust input for 0 dBm.		3.0	-45	dB
			$R_L = 600 \Omega$ , $C_L = 50 pF$ , $f_{IN} = 1 MHz$ , sine wave Figure 6		4.5	-45	

Note: These characteristics are determined by design of devices.



#### 12. AC Test Circuit



Cont : Control Inputs A or B or C or INH (C:Except VHC4052A)

P.G. : Pulse generator

Figure 1 t<sub>PLZ</sub>, t<sub>PHZ</sub>, t<sub>PZL</sub>, t<sub>PZH</sub>

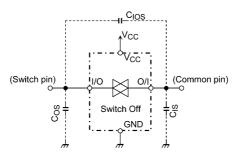


Figure 2 CIOS, CIS, COS

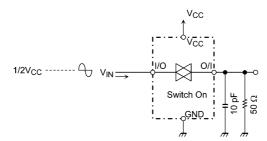


Figure 3 Frequency Response

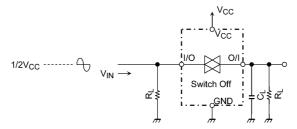
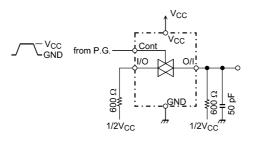


Figure 4 Feedthrough Attenuation





Cont : Control Inputs A or B or C or INH (C:Except VHC4052A)

P.G. : Pulse generator

Figure 5 Cross Talk (control input to output signal)

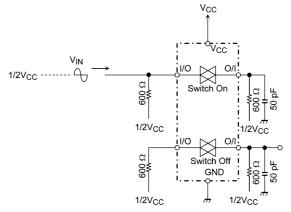
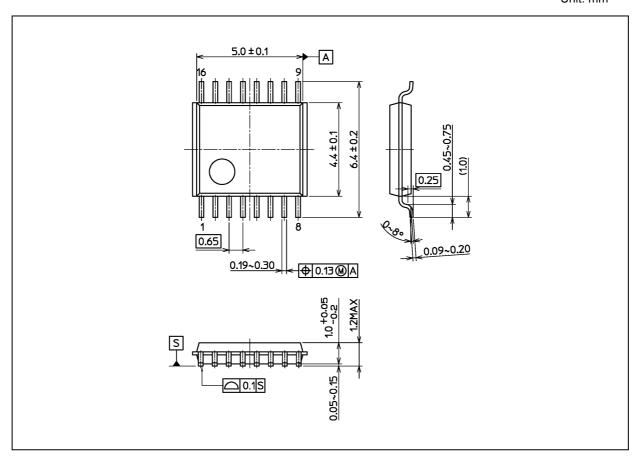


Figure 6 Cross Talk (between any two switches)



## **Package Dimensions**

Unit: mm



Weight: 0.055 g (typ.)

	Package Name(s)
Nickname: TSSOP16B	



## 74VHC4051AFT,74VHC4052AFT,74VHC4053AFT

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